

UTC UNISONIC TECHNOLOGIES CO., LTD

05N30

Power MOSFET

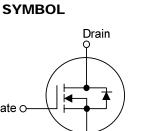
0.5A, 300V N-CHANNEL **POWER MOSFET**

DESCRIPTION

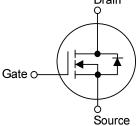
The UTC 05N30 is a N-channel mode power MOSFET using UTC's advanced technology to provide customers with a minimum on-state resistance, low gate charge and superior switching performance.

FEATURES

- * $R_{DS(ON)} \le 5.0 \Omega$ @ $V_{GS}=10V$, $I_D=0.25A$
- * High switching speed
- * 100% avalanche tested



1 TO-220F1 SOT-23 (EIAJ SC-59)

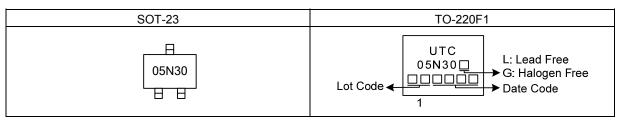


ORDERING INFORMATION

Ordering Number		Deekage	Pin Assignment			Deaking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
05N30L-AE3-R	05N30G-AE3-R	SOT-23	G	S	D	Tape Reel	
05N30L-TF1-T	05N30G-TF1-T	TO-220F1	G	D	S	Tube	
Note: Pin Assignment: G: Gate S: Source D: Drain							

05N30 <u>G-AE3-R</u>	
(1)Packing Type	(1) R: Tape Reel, T: Tube
(2)Package Type	(2) AE3: SOT-23, TF1:TO-220F1
(3)Green Package	(3) G: Halogen Free and Lead Free, L: Lead Free

MARKING



■ ABSOLUTE MAXIMUM RATINGS (T_C=25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		V _{DSS}	300	V
Gate-Source Voltage		V _{GSS}	±30	V
Continuous Drain Current		I _D	0.5	А
Pulsed Drain Current (Note 2)		I _{DM}	2.0	А
Power Dissipation	SOT-23	D	0.6	W
	TO-220F1	- P _D	15	W
Junction Temperature		TJ	+150	°C
Storage Temperature		T _{STG}	-55 ~ +150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Repetitive Rating: Pulse width limited by maximum junction temperature.

THERMAL DATA

PARAMETER		SYMBOL	RATINGS	UNIT
lunction to Ambient	SOT-23	0	325	°C/W
Junction to Ambient	TO-220F1	θ_{JA}	625	°C/W
lunction to Conc	SOT-23	0	208	°C/W
Junction to Case	TO-220F1	θ _{JC}	8.33	°C/W

Note: Device mounted on FR-4 substrate P_C board, 2oz copper, with 1inch square copper plate.

■ ELECTRICAL CHARACTERISTICS (T_J =25°C, unless otherwise specified)

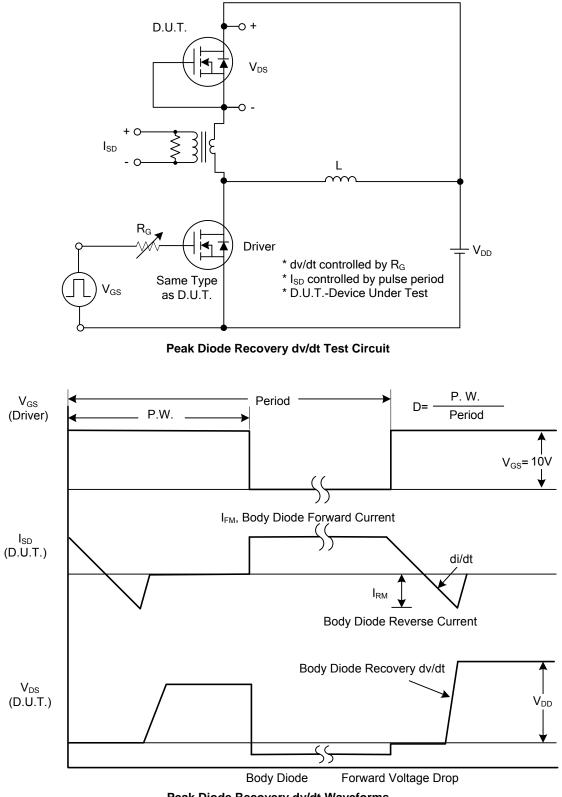
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PARAMETER		SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage		BV_{DSS}	I _D =250μA, V _{DS} =0V	300			V
Drain-Source Leakage Current		I _{DSS}	V _{DS} =300V			10	μA
Gate-Source Leakage Current	Forward	- I _{GSS}	V _{GS} =+30V, V _{DS} =0V			100	nA
	Reverse		V_{GS} =-30V, V_{DS} =0V			-100	nA
ON CHARACTERISTICS							
Gate Threshold Voltage		V _{GS(TH)}	I _D =250μA			3.0	V
Static Drain-Source On-State Re	esistance	R _{DS(ON)}	V _{GS} =10V, I _D =0.25A			5.0	Ω
DYNAMIC PARAMETERS							
Input Capacitance		CISS			100		pF
Output Capacitance Reverse Transfer Capacitance		Coss	V _{GS} =0V, V _{DS} =25V, f=1MHz		20		pF
		C _{RSS}			3.2		pF
SWITCHING PARAMETERS							
Total Gate Charge (Note 1)		Q_G	V_{DS} =240V, V_{GS} =10V, I_D =0.5A		8.5		nC
Gate to Source Charge		Q_{GS}			2.2		nC
Gate to Drain Charge		Q_{GD}	V_{DS} =240V, V_{GS} =10V, I_{D} =0.5A I_{G} = 1m A (Note1, 2)		1.2		nC
Turn-ON Delay Time (Note 1)		t _{D(ON)}			4		ns
Rise Time		t _R	V _{DS} =150V, V _{GS} =10V, I _D =0.5A,		17		ns
Turn-OFF Delay Time		t _{D(OFF)}	R _G =25Ω (Note1, 2)		9		ns
Fall-Time		t _F			20		ns
SOURCE- DRAIN DIODE RATII	NGS AND CH	ARACTERIS	TICS				
Maximum Body-Diode Continuo	us Current	ls				0.5	Α
Maximum Body-Diode Pulsed Current		I _{SM}				2.0	Α
Drain-Source Diode Forward Vo	ltage (Note 1)	V_{SD}	I _S =0.5A, V _{GS} =0V			1.4	V
Reverse Recovery Time (Note 1)	t _{rr}	I _S =0.5A , V _{GS} =0V		65		ns
Reverse Recovery Charge		Q _{rr}	di/dt=100A/µs		75		μC
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Notes: 1. Pulse Test : Pulse width \leq 300µs, Duty cycle \leq 2%.

2. Essentially independent of operating temperature.

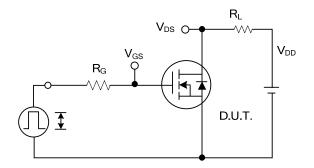


TEST CIRCUITS AND WAVEFORMS

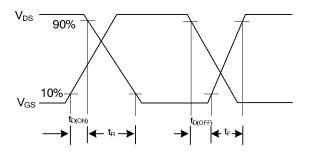




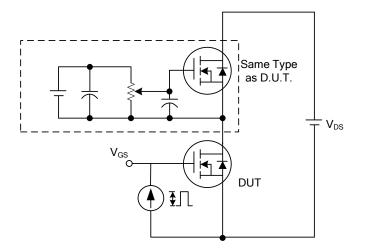
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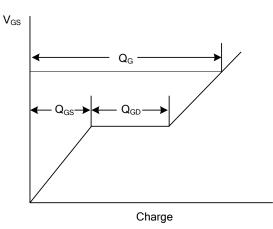




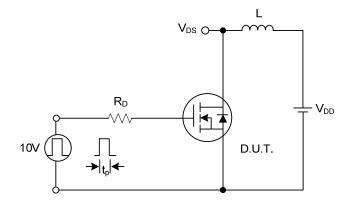
Switching Waveforms



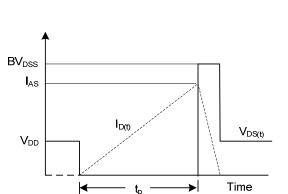
Gate Charge Test Circuit



Gate Charge Waveform



Unclamped Inductive Switching Test Circuit

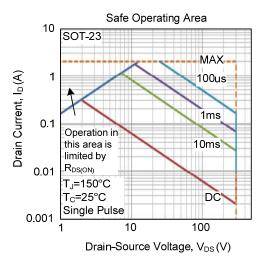


Unclamped Inductive Switching Waveforms

t_p



TYPICAL CHARACTERISTICS



UTC assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all UTC products described or contained herein. UTC products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. UTC reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

